

CMOS Digital Integrated Circuits Silicon Monolithic

TC74AC00FT

1. Functional Description

• Quad 2-Input NAND Gate

2. General

The TC74AC00FT is an advanced high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

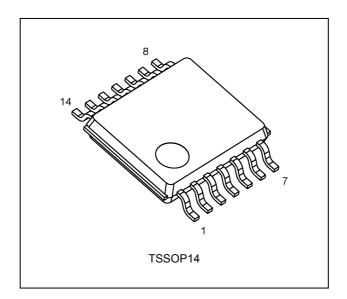
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

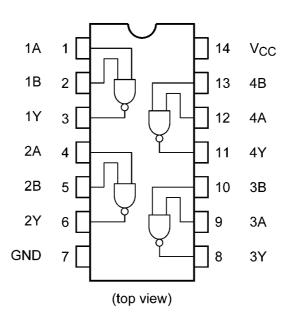
3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: t_{pd} = 3.8 ns (typ.) V_{CC} = 5.0 V
- (3) Low power dissipation: $I_{CC} = 4.0 \ \mu A \ (max) T_a = 25 \ ^{\circ}C$
- (4) High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$ (min)
- (5) Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 4.5 \text{ V})$
- (6) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (7) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V to } 5.5 \text{ V}$
- (8) Pin and function compatible with 74F00.
- Note 1: Operating Range spec of Topr = -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.

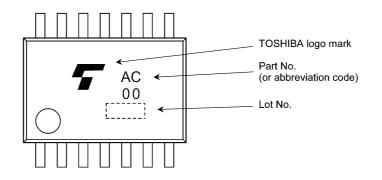
4. Packaging



5. Pin Assignment



6. Marking



7. IEC Logic Symbol

1A <u>(1)</u> 1B <u>(2)</u>	&	(<u>3)</u> 1Y
2A <u>(4)</u> 2B <u>(5)</u>		<u>(6)</u> 2Y
3A <u>(9)</u> 3B <u>(10)</u>		<u>(8)</u> 3Y
4A <u>(12)</u> 4B <u>(13)</u>		<u>(11)</u> 4Y

8. Truth Table

А	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{ОК}		±50	mA
Output current	I _{OUT}		±50	mA
V _{CC} /ground current	I _{CC}		±100	mA
Power dissipation	PD	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Note		Rating	Unit
Supply voltage	V _{CC}			2.0 to 5.5	V
Input voltage	V _{IN}			0 to V _{CC}	V
Output voltage	V _{OUT}			0 to V _{CC}	V
Operating temperature	T _{opr}	(Note 1)		-40 to 125	Ĵ
Input rise and fall times	dt/dv		V_{CC} = 3.3 \pm 0.3 V	0 to 100	ns/V
			V_{CC} = 5.0 \pm 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of Topr = -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	n	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	VIH	_		2.0	1.50	_	_	V
				3.0	2.10	_	_	1
				5.5	3.85	_	_	
Low-level input voltage	VIL	—		2.0	_	_	0.50	V
				3.0	_	_	0.90	
				5.5	_	_	1.65	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -4 mA	3.0	2.58	_	_	
			I _{OH} = -24 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 12 mA	3.0	_	_	0.36	
			I _{OL} = 24 mA	4.5		_	0.36	
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	±0.1	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μA

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Conditio	n	Note	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_			2.0	1.50		V
					3.0	2.10]
					5.5	3.85	_	
Low-level input voltage	VIL	_			2.0	_	0.50	V
					3.0	_	0.90	
					5.5	_	1.65	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA		2.0	1.9		V
					3.0	2.9		
					4.5	4.4	_	
			I _{OH} = -4 mA		3.0	2.48	_	
			I _{OH} = -24 mA		4.5	3.80	_	
			I _{OH} = -75 mA	(Note 1)	5.5	3.85	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA		2.0		0.1	V
					3.0	_	0.1	
					4.5	_	0.1	
			I _{OL} = 12 mA		3.0		0.44	
			I _{OL} = 24 mA		4.5		0.44	
			I _{OL} = 75 mA	(Note 1)	5.5		1.65	
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND			5.5		±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND			5.5	_	40.0	μA

Note 1: This spec indicates the capability of driving 50 $\boldsymbol{\Omega}$ transmission lines.

One output should be tested within a 10 ms maximum duration.

11.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditio	n	Note	V _{CC} (V)	Min	Max	Unit
High-level input voltage	VIH	—			2.0	1.50	_	V
					3.0	2.10	_	
					5.5	3.85		
Low-level input voltage	VIL	—			2.0		0.50	V
					3.0		0.90	
					5.5		1.65	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA		2.0	1.9	_	V
					3.0	2.9		
					4.5	4.4	_]
			I _{OH} = -4 mA		3.0	2.48	_	
			I _{OH} = -24 mA		4.5	3.70	_	
			I _{OH} = -50 mA	(Note 1)	5.5	3.85		
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA		2.0	_	0.1	V
					3.0	_	0.1	
					4.5		0.1	
			I _{OL} = 12 mA		3.0	_	0.44	
			I _{OL} = 24 mA		4.5	_	0.50]
			I _{OL} = 50 mA	(Note 1)	5.5	_	1.65	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND			5.5	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND			5.5	_	80.0	μA

Note: Operating Range spec of Topr = -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.

Note 1: This spec indicates the capability of driving 50 Ω transmission lines. One output should be tested within a 10 ms maximum duration.

11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		C _L = 50 pF	$\textbf{3.3}\pm\textbf{0.3}$	_	6.6	11.2	ns
			R _L = 500 Ω	5.0 ± 0.5	_	4.9	7.0	
Input capacitance	C _{IN}		—		_	5	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)	—		_	68	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate)

11.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	C _L = 50 pF	$\textbf{3.3}\pm\textbf{0.3}$	1.0	12.9	ns
		R _L = 500 Ω	5.0 ± 0.5	1.0	8.0	
Input capacitance	C _{IN}	_			10	pF

11.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

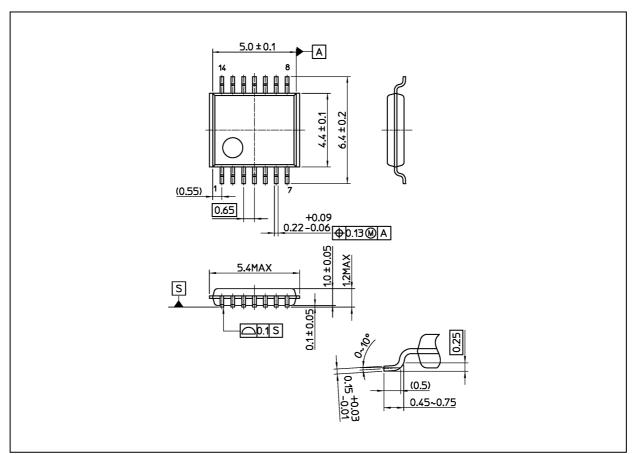
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	C _L = 50 pF	$\textbf{3.3}\pm\textbf{0.3}$	1.0	14.1	ns
		R _L = 500 Ω	5.0 ± 0.5	1.0	8.7	
Input capacitance	C _{IN}			_	10	рF

Note: Operating Range spec of Topr = -40 °C to 125 °C is applicable only for the products which manufactured after January 2020.

TC74AC00FT

Package Dimensions

Unit: mm



Weight: 0.06 g (typ.)

	Package Name(s)
Nickname: TSSOP14	

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